

CY621282BN MoBL® Automotive 1-Mbit (128 K × 8) Static RAM

Features

- Temperature Ranges
 □ Automotive-E: -40 °C to 125 °C
- 4.5 V to 5.5 V operation
- Complementary metal oxide semiconductor (CMOS) for optimum speed/power
- Low active power 137.5 mW (max.) (25 mA)
- Low standby power 137.5 μW (max.) (25 μA)
- Automatic power-down when deselected
- TTL-compatible inputs and outputs
- Easy memory expansion with \overline{CE}_1 , CE_2 , and \overline{OE} options
- Available in Pb-free 32-pin (450 mil-wide) small outline integrated circuit (SOIC) package

Functional Description

The CY621282BN is a high-performance CMOS static RAM organized as 128K words by 8 bits. Easy memory expansion is provided by an active LOW Chip Enable ($\overline{\text{CE}}_1$), an active HIGH Chip Enable ($\overline{\text{CE}}_2$), and active LOW Output Enable ($\overline{\text{OE}}$). This device has an automatic power-down feature that reduces power consumption by more than 75% when deselected.

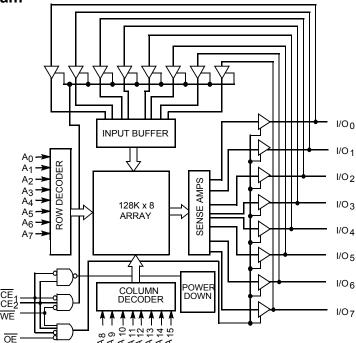
Writing to the device is accomplished by taking Chip Enable One (\overline{CE}_1) and Write Enable (\overline{WE}) inputs LOW and Chip Enable Two (\overline{CE}_2) input HIGH. Data on the eight I/O pins $(I/O_0$ through $I/O_7)$ is then written into the location specified on the address pins $(A_0$ through $A_{16})$.

Reading from the device is accomplished by taking Chip Enable One $(\overline{\text{CE}_1})$ and Output Enable $(\overline{\text{OE}})$ LOW while forcing Write Enable $(\overline{\text{WE}})$ and Chip Enable Two $(\overline{\text{CE}_2})$ HIGH. Under these conditions, the contents of the memory location specified by the address pins will appear on the I/O pins.

The eight input/output pins (I/O₀ through I/O₇) are placed in a high-impedance state when the device is <u>des</u>elected (\overline{CE}_1 HIGH or \overline{CE}_2 LOW), the outputs are disabled (\overline{OE} HIGH), or during a write operation (\overline{CE}_1 LOW, \overline{CE}_2 HIGH, and \overline{WE} LOW).

For a complete list of related resources, click here.

Logic Block Diagram



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198 Champion Court

San Jose, CA 95134-1709

408-943-2600

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CY621282BN MoBL® Automotive

Contents

Product Portfolio	3
Pin Configuration	3
Pin Definitions	
Maximum Ratings	4
Operating Range	
Electrical Characteristics	
Capacitance	5
Thermal Resistance	
AC Test Loads and Waveforms	5
Data Retention Waveform	
Data Retention Characteristics	
Switching Characteristics	7
Switching Waveforms	
Truth Table	10

Ordering information	10
Ordering Code Definitions	10
Package Diagrams	
Acronyms	12
Document Conventions	12
Units of Measure	12
Document History Page	13
Sales, Solutions, and Legal Information	
Worldwide Sales and Design Support	14
Products	14
PSoC® Solutions	14
Cypress Developer Community	14
Technical Support	

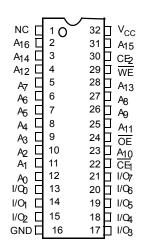


Product Portfolio

		V _{CC} Range (V)				Power Dissipation				
Pro	duct				Speed (ns)	Operating, I _{CC} (mA)		Standby, I _{SB2} (μA)		
		Min	Typ ^[1]	Max		Typ ^[1]	Max	Typ ^[1]	Max	
CY621282BN	Automotive-E	4.5	5.0	5.5	70	6	25	2.5	25	

Pin Configuration

Figure 1. 32-pin SOIC (Top View)



Pin Definitions

I/O Type	Description
Input	A ₀ -A ₁₆ . Address inputs
Input/output	I/O ₀ -I/O ₇ . Data lines. Used as input or output lines depending on operation.
Input/control	WE . Write Enable, Active LOW. When selected LOW, a WRITE is conducted. When selected HIGH, a READ is conducted.
Input/control	CE ₁ . Chip Enable 1, Active LOW.
Input/control	CE2. Chip Enable 2, Active HIGH.
Input/control	OE . Output Enable, Active LOW. Controls the direction of the I/O pins. When LOW, the I/O pins behave as outputs. When deasserted HIGH, I/O pins are tri-stated, and act as input data pins.
Ground	GND. Ground for the device.
Power supply	V _{CC} . Power supply for the device.

Note

^{1.} Typical values are included for reference only and are not tested or guaranteed. Typical values are measured at V_{CC} = 5.0 V, T_A = 25 °C.



Maximum Ratings

Exceeding maximum ratings may impair the useful life of the device. These user guidelines are not tested. Ambient temperature with Supply voltage on V_{CC} to relative $\mbox{GND}^{\mbox{\scriptsize [2]}}$ -0.5 V to +7.0 V

DC input voltage ^[2, 3]	0.5 V to V _{CC} + 0.5 V
Current into outputs (LOW)	20 mA
Static discharge voltage (per MIL-STD-883, Method 3015)	> 2001 V
Latch-up current	> 200 mA

Operating Range

Range	Ambient Temperature	V _{CC}
Automotive-E	–40 °C to +125 °C	5 V ± 10%

Electrical Characteristics

Over the Operating Range

Downwoodow	Description	Took Conditions	-70				
Parameter	Description	Test Conditions	Min	Typ ^[4]	Max	Unit	
V _{OH}	Output HIGH voltage	V _{CC} = 4.5 V, I _{OH} = -1.0 mA	2.4	_	_	V	
		$V_{CC} = 5.5 \text{ V}, I_{OH} = -0.1 \text{ mA}$	3.95	_	_		
		$V_{CC} = 5 \text{ V}, I_{OH} = -0.1 \text{ mA}$	3.6	_	_		
		V_{CC} = 4.5 V, I_{OH} = -0.1 mA	3.25	_	_		
V_{OL}	Output LOW voltage	V _{CC} = 4.5 V, I _{OL} = 2.1 mA	-	_	0.4	V	
V _{IH}	Input HIGH voltage		2.2	_	V _{CC} + 0.3	V	
V_{IL}	Input LOW voltage ^[2]		-0.3	_	0.8	V	
I _{IX}	Input leakage current	$GND \le V_{IN} \le V_{CC}$	-10	_	+10	μΑ	
I _{OZ}	Output leakage current	$GND \le V_{IN} \le V_{CC}$, Output Disabled	-10	_	+10	μΑ	
I _{CC}	V _{CC} operating supply current	$f = f_{MAX} = 1/t_{RC}$ $V_{CC} = 5.5 V$,	-	6	25	mA	
		$f = 1 \text{ MHz}$ $I_{OUT} = 0 \text{ mA}$		2	12		
I _{SB1}	Automatic CE power-down current – TTL inputs	$V_{CC} = 5.5 \text{ V}, \overline{CE}_1 \ge V_{IH} \text{ or } CE_2 \le V_{IL}, V_{IN} \ge V_{IH} \text{ or } V_{IN} \le V_{IL}, f = f_{MAX}$	_	0.1	2	mA	
I _{SB2}	Automatic CE power-down current – CMOS inputs	$\begin{array}{c} V_{CC} = 5.5 \text{ V}, \ \overline{CE}_1 \geq V_{CC} - 0.3 \text{ V}, \\ \text{or } CE_2 \leq 0.3 \text{ V}, \ V_{IN} \geq V_{CC} - 0.3 \text{ V}, \text{ or } \\ V_{IN} \leq 0.3 \text{ V}, \ f = 0 \end{array}$	-	2.5	25	μА	

- 2. V_{IL} (min.) = -2.0 V for pulse durations of less than 20 ns.
 3. No input may exceed V_{CC} + 0.5 V.
 4. Typical values are included for reference only and are not tested or guaranteed. Typical values are measured at V_{CC} = 5.0 V, T_A = 25 °C.

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Capacitance

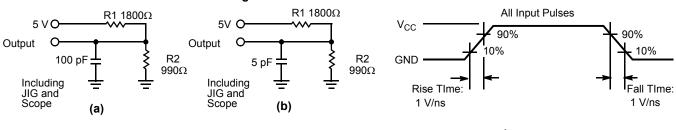
Parameter [5]	Description	Test Conditions	Max	Unit
C _{IN}	Input capacitance	$T_A = 25 ^{\circ}\text{C}, f = 1 \text{MHz}, V_{CC} = 5.0 \text{V}$	9	pF
C _{OUT}	Output capacitance		9	pF

Thermal Resistance

Parameter [5]	Description	Test Conditions	32-pin SOIC	Unit
Θ_{JA}	Thermal resistance (junction to ambient)	Test conditions follow standard test methods and procedures for measuring thermal impedance, per EIA /	66.17	°C/W
$\Theta_{\sf JC}$	Thermal resistance (junction to case)	1JESD51.	30.87	°C/W

AC Test Loads and Waveforms

Figure 2. AC Test Loads and Waveforms



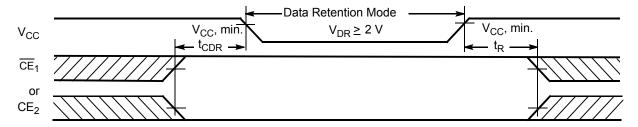


Note
5. Tested initially and after any design or process changes that may affect these parameters.



Data Retention Waveform

Figure 3. Data Retention Waveform



Data Retention Characteristics

Over the Operating Range

Parameter	Description	Condition	Conditions		Тур	Max	Unit
V_{DR}	V _{CC} for data retention			2.0	_	_	V
I _{CCDR}	Data retention current	$\begin{array}{l} \frac{V_{CC}}{CE_1} = V_{DR} = 2.0 \text{ V,} \\ CE_1 \geq V_{CC} - 0.3 \text{ V, or} \\ CE_2 \leq 0.3 \text{ V,} \\ V_{IN} \geq V_{CC} - 0.3 \text{ V or,} \\ V_{IN} \leq 0.3 \text{ V} \end{array}$	Automotive-E	-	1.5	25	μА
t _{CDR}	Chip deselect to data retention time			0	_	-	ns
t _R	Operation recovery time			70	_	_	ns



Switching Characteristics

Over the Operating Range

Parameter [6]	Dog animation	CY6212	CY621282BN-70		
Parameter [9]	Description	Min	Max	Unit	
Read Cycle			•	•	
t _{RC}	Read cycle time	70	_	ns	
t _{AA}	Address to data valid	_	70	ns	
t _{OHA}	Data hold from address change	5	_	ns	
t _{ACE}	CE ₁ LOW to data valid, CE ₂ HIGH to data valid	_	70	ns	
t _{DOE}	OE LOW to data valid	_	35	ns	
t _{LZOE}	OE LOW to Low Z [7]	0	_	ns	
t _{HZOE}	OE HIGH to High Z [7, 8]	_	25	ns	
t _{LZCE}	CE ₁ LOW to Low Z, CE ₂ HIGH to Low Z ^[7]	5	_	ns	
t _{HZCE}	CE ₁ HIGH to High Z, CE ₂ LOW to High Z [7, 8]	_	25	ns	
t _{PU}	CE ₁ LOW to Power-up, CE ₂ HIGH to power-up	0	_	ns	
t _{PD}	CE ₁ HIGH to Power-down, CE ₂ LOW to power-down	_	70	ns	
Write Cycle [9,	10]	<u>.</u>			
t _{WC}	Write cycle time	70	_	ns	
t _{SCE}	CE ₁ LOW to Write End, CE ₂ HIGH to write end	60	_	ns	
t _{AW}	Address set-up to write end	60	_	ns	
t _{HA}	Address hold from write end	0	_	ns	
t _{SA}	Address set-up to write start	0	_	ns	
t _{PWE}	WE pulse width	50	_	ns	
t _{SD}	Data set-up to write end	30	_	ns	
t _{HD}	Data Hold from write end	0	_	ns	
t _{LZWE}	WE HIGH to Low Z [7]	5	_	ns	
t _{HZWE}	WE LOW to High Z [7, 8]	_	25	ns	

Notes

Test conditions assume signal transition time of 5 ns or less, timing reference levels of 1.5 V, input pulse levels of 0 to 3.0 V, and output loading of the specified I_{OL}/I_{OH} and 100-pF load capacitance.

At any given temperature and voltage condition, t_{HZCE} is less than t_{LZCE}, t_{HZOE} is less than t_{LZOE}, and t_{HZWE} is less than t_{LZWE} for any given device.

t_{HZCE}, t_{HZCE}, and t_{HZWE} are specified with a load capacitance of <u>5 p</u>F as in (b) of Figure 2 on page 5. Transition is measured ±500 mV from steady-state voltage. The internal write time of the memory is defined by the overlap of CE₁ LOW, CE₂ HIGH, and WE LOW. CE₁ and WE must be LOW and CE₂ HIGH to initiate a write, and the transition of any of these signals can terminate the write. The input data set-up and hold timing should be referenced to the leading edge of the signal that terminates the write.

^{10.} The minimum write cycle pulse width for Write Cycle No. 3 (WE controlled, OE LOW) should be equal to the sum of tsD and tHZWE.



Switching Waveforms

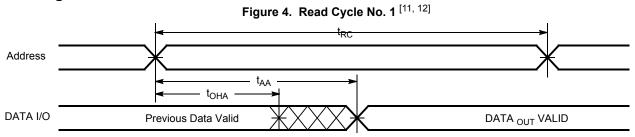


Figure 5. Read Cycle No. 2 (OE Controlled) [12, 13]

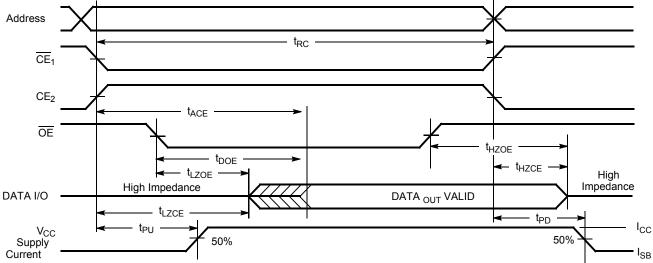
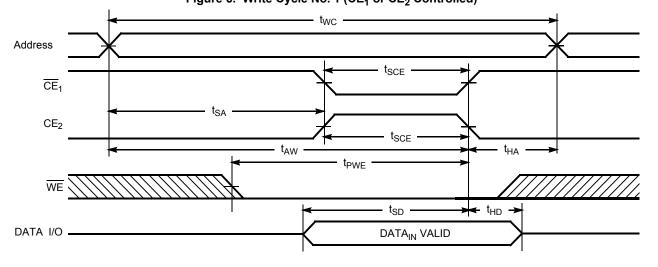


Figure 6. Write Cycle No. 1 ($\overline{\text{CE}}_1$ or CE_2 Controlled) [14, 15]



- 11. Device is continuously selected. \overline{OE} , $\overline{CE}_1 = V_{IL}$, $CE_2 = V_{IH}$.

 12. WE is HIGH for read cycle.

- 12. We is filed to read cycle.
 13. Address valid prior to or coincident with CE₁ transition LOW and CE₂ transition HIGH.
 14. Data I/O is high impedance if OE = V_{IH}.
 15. If CE₁ goes HIGH or CE₂ goes LOW simultaneously with WE going HIGH, the output remains in a high-impedance state.



Switching Waveforms (continued)

Figure 7. Write Cycle No. 2 (WE Controlled, OE HIGH during Write) [16, 17]

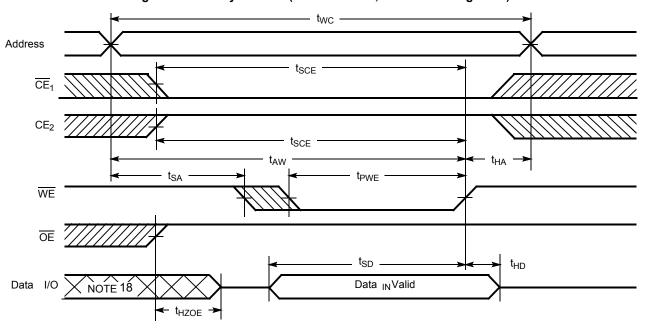
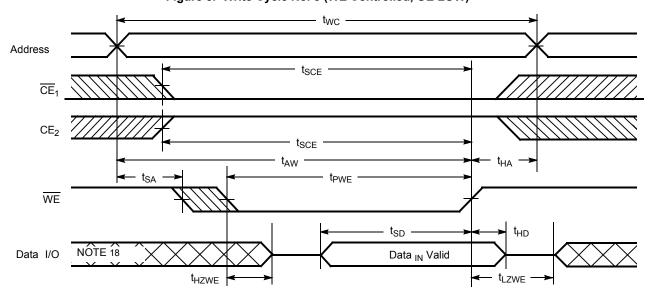


Figure 8. Write Cycle No. 3 (WE Controlled, OE LOW) [16, 17, 19]



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Truth Table

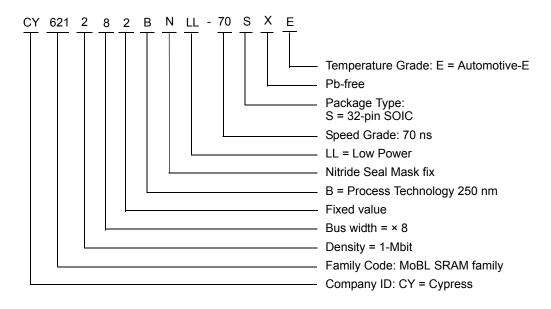
CE ₁	CE ₂	OE	WE	I/O ₀ -I/O ₇	Mode	Power
Н	Х	Х	Х	High Z	Power-down	Standby (I _{SB})
Х	L	Χ	Х	High Z	Power-down	Standby (I _{SB})
L	Н	L	Н	Data out	Read	Active (I _{CC})
L	Н	Х	L	Data in	Write	Active (I _{CC})
L	Н	Н	Н	High Z	Selected, Outputs disabled	Active (I _{CC})

Ordering Information

Speed (ns)		Ordering Code	Package Diagram	Package Type	Operating Range
	70	CY621282BNLL-70SXE 51-85081		32-pin 450-Mil SOIC (Pb-free)	Automotive-E

Please contact your local Cypress sales representative for availability of these parts.

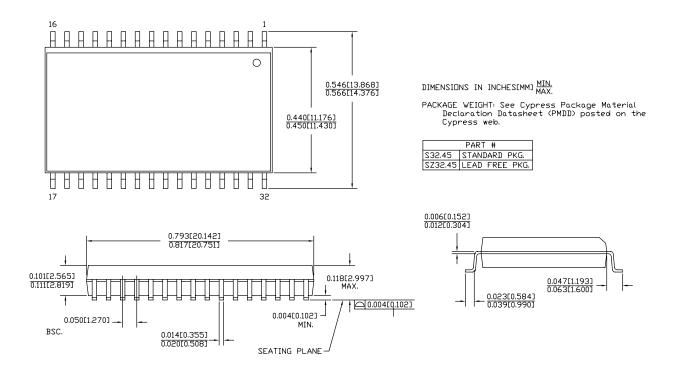
Ordering Code Definitions





Package Diagrams

Figure 9. 32-pin Molded SOIC (450 Mils) S32.45/SZ32.45, 51-85081



51-85081 *E



Acronyms

Acronym	Description			
CE	Chip Enable			
CMOS	Complementary Metal Oxide Semiconductor			
I/O	Input/Output			
ŌĒ	Output Enable			
SOIC	Small Outline Integrated Circuit			
SRAM	Static Random Access Memory			
TTL	Transistor-Transistor Logic			
WE	Write Enable			

Document Conventions

Units of Measure

Symbol	Unit of Measure			
°C	degree Celsius			
MHz	megahertz			
μΑ	microampere			
μS	microsecond			
mA	milliampere			
mV	millivolt			
mW	milliwatt			
ns	nanosecond			
Ω	ohm			
%	percent			
pF	picofarad			
V	volt			
W	watt			



Document History Page

	ocument Title: CY621282BN MoBL [®] Automotive, 1-Mbit (128 K × 8) Static RAM ocument Number: 001-65526							
Rev.	ECN No.	Issue Date	Orig. of Change	Description of Change				
**	3115909	01/06/2011	RAME	New data sheet.				
*A	3288690	06/21/2011	RAME	Updated Functional Description: Removed the Note "For best-practice recommendations, please refer to the Cypress application note "System Design Guidelines" on http://www.cypress.com website." and its reference. Updated to new template.				
*B	3538379	03/05/2012	TAVA	Updated Electrical Characteristics. Updated Switching Waveforms. Updated Package Diagrams.				
*C	4703739	03/27/2015	MEMJ	Updated Switching Characteristics: Added Note 10 and referred the same note in "Write Cycle". Updated Switching Waveforms: Added Note 19 and referred the same note in Figure 8. Updated Package Diagrams: spec 51-85081 – Changed revision from *D to *E. Updated to new template. Completing Sunset Review.				
*D	4725832	04/15/2015	PSR	Updated Functional Description: Added "For a complete list of related resources, click here." at the end.				



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